

OKI semiconductor

MSM5165RS/JS

8,192-WORD x 8-BIT CMOS STATIC RAM (E3-S-017-32)

GENERAL DESCRIPTION

The MSM5165RS/JS is a 8192-word by 8-bit CMOS static RAM featuring 5V power supply operation and direct TTL input/output compatibility. Since the circuitry is completely static, external clock and refreshing operations are unnecessary, making this device very easy to use. The MSM5165RS/JS is also a CMOS silicon gate device which requires very low power during standby (standby current of 1mA) when there is no chip selection.

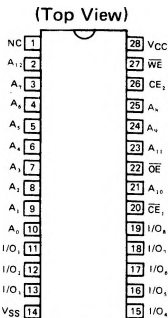
A byte system is adopted, and since there is pin compatibility with standard ultra-violet EPROMs, this device is ideal for use as a peripheral memory for microcomputers and data terminal units etc. In addition, \overline{CE}_1 , CE_2 , and \overline{OE} signals enable OR ties with the output terminals of other chips, thereby facilitating simple memory expansion and bus line control etc.

FEATURES

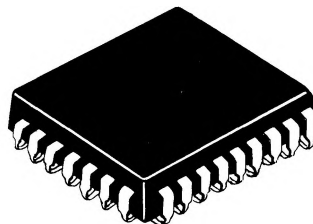
- Single 5V Supply
- $0^\circ\text{C} \sim 70^\circ\text{C}$
- Low Power Dissipation
 - Standby; 5.5 mW MAX
 - Operation; 248 mW MAX
- High Speed (Equal Access and Cycle Time)
 - 120 – 200 ns MAX
- Direct TTL Compatible. (Input and Output)
- 3-State Output
- Pin Compatible with
 - 64K EPROM (MSM2764)
 - 28-pin DIP PKG
 - 32-pin PLCC



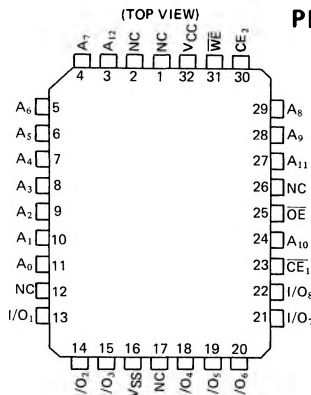
PIN CONFIGURATION



$A_0 \sim A_{12}$: Address INPUTS
 $I/O_1 \sim I/O_8$: Data Input/Output
 \overline{CE}_1, CE_2 : Chip Select
 WE : Write Enable
 \overline{OE} : Output Enable
 V_{CC}, V_{SS} : Supply Voltage

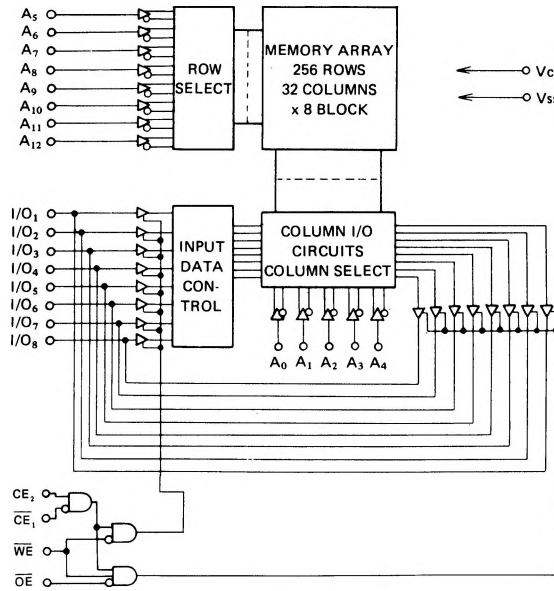


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FUNCTIONAL BLOCK DIAGRAM



TRUTH TABLE

Mode	\overline{CE}_1	CE_2	\overline{WE}	\overline{OE}	I/O Operation
Standby	H	X	X	X	High Z
	X	L	X	X	
Read	L	H	H	H	High Z
	L	H	H	L	D _{OUT}
Write	L	H	L	X	D _{IN}

X : H or L

ABSOLUTE MAXIMUM RATINGS

Rating	Symbol	Value	Unit	Conditions
Supply Voltage	V _{CC}	-0.3 to 7.0	V	Respect to GND
Input Voltage	V _{IN}	-0.3 to V _{CC} + 0.3	V	
Operating Temperature	T _{opr}	0 to 70	°C	
Storage Temperature	T _{stg}	-55 to 150	°C	
Power Dissipation	P _D	1.0	W	T _a = 25°C

RECOMMENDED OPERATING CONDITION

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Supply Voltage	V _{CC}	4.5	5	5.5	V	5V ± 10%
	V _{SS}		0		V	
Input Voltage	V _{IH}	2.2		V _{CC} + 0.3	V	5V ± 10%
	V _{IL}	-0.3		0.8	V	
Output Load	C _L			100	pF	
	TTL			1		

DC CHARACTERISTICS(V_{CC} = 5V ± 10%, T_a = 0°C to +70°C)

Parameter	Symbol	MSM5165			Unit	Test Condition
		Min.	Typ.	Max.		
Input Leakage Current	I _{LI}	-1		1	μA	V _{IN} = 0 to V _{CC}
Output Leakage Current	I _{LO}	-1		1	μA	$\overline{CE}_1 = V_{IH}$ or $CE_2 = V_{IL}$ or $\overline{OE} = V_{IH}$ V _{I/O} = 0 to V _{CC}
Output Voltage	V _{OH}	2.4			V	I _{OH} = -1 mA
	V _{OL}			0.4	V	I _{OL} = 2.1 mA
Standby Supply Current	I _{CCS}		0.02	1	mA	$\overline{CE}_1 \geq V_{CC} - 0.2V$, $CE_2 \geq V_{CC} - 0.2V$ V _{IN} = 0 to V _{CC} $CE_2 \leq 0.2V$ V _{IN} = 0 to V _{CC}
	I _{CCS1}			3	mA	$\overline{CE}_1 = V_{IH}$, $CE_2 = V_{IL}$ t _{cyc} = Min, cycle
Operating Supply Current	I _{CCA}			①	mA	T _{CYC} = Min, cycle
				15		T _{CYC} = 1 μs

5165-12 55 mA 5165-15 50 mA 5165-20 45 mA

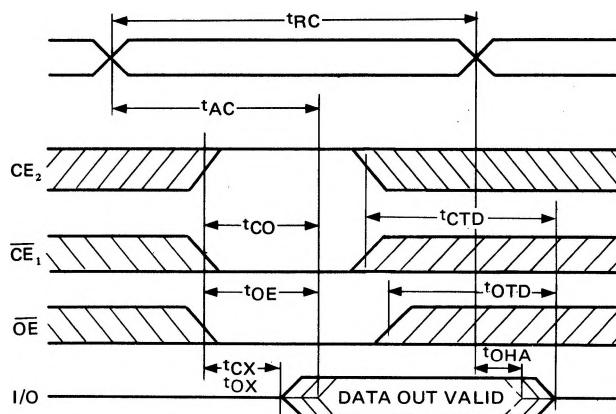
AC CHARACTERISTICS**Test Condition**

Parameter	Conditions
Input Pulse Level	V _{IH} = 2.4V, V _{IL} = 0.6V
Input Rise and Fall Times	10 ns
Input and Output Timing Reference Level	1.5V
Output Load	C _L = 100 pF, 1 TTL Gate

READ CYCLE(V_{CC} = 5V ± 10%, T_a = 0°C to 70°C)

Parameter	Symbol	MSM5165-12		MSM5165-15		MSM5165-20		Unit
		Min.	Max.	Min.	Max.	Min.	Max.	
Read Cycle Time	t _{RC}	120		150		200		ns
Address Access Time	t _{AC}		120		150		200	ns
Chip Enable Access Time	t _{CO}		120		150		200	ns
Output Enable to Output Valid	t _{OE}		60		70		90	ns
Chip Selection to Output Active	t _{CX}	10		10		10		ns
Output Hold Time From Address Change	t _{OHA}	10		15		20		ns
Output Enable to Output Active	t _{OX}	5		5		5		ns
Output 3-state from Output Disable	t _{OTD}	0	40	0	50	0	60	ns
Output 3-state from Chip Deselection	t _{CTD}	0	60	0	70	0	80	ns

READ CYCLE



- Notes:**
1. A Read occurs during the overlap of a low \overline{CE}_1 , a high CE_2 , a low \overline{OE} and a high \overline{WE} .
 2. t_{CX} is specified from \overline{CE}_1 , CE_2 or \overline{OE} , whichever occurs last.
 3. t_{OTD} is specified from \overline{CE}_1 , CE_2 or \overline{OE} , whichever occurs first.
 4. t_{OHA} and t_{OTD} are specified by the time when DATA OUT is floating.

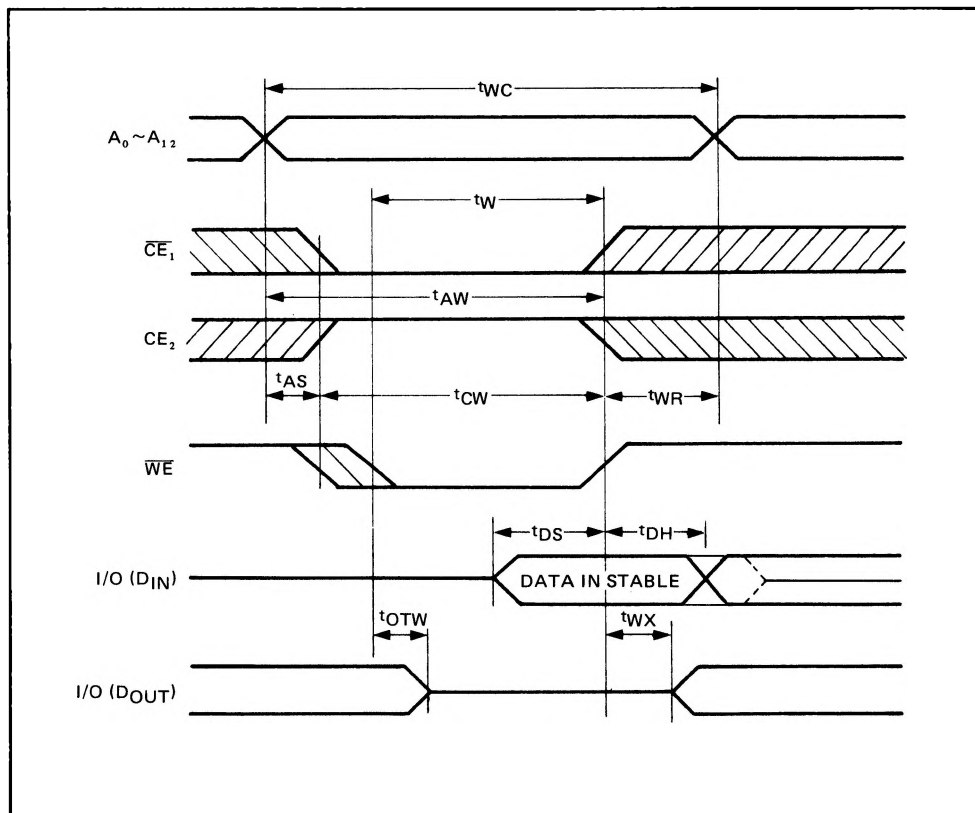
WRITE CYCLE

($V_{CC} = 5V \pm 10\%$, $T_a = 0^\circ C$ to $+70^\circ C$)

Item	Symbol	MSM5165-12		MSM5165-15		MSM5165-20		Unit
		Min.	Max.	Min.	Max.	Min.	Max.	
Write Cycle Time	t_{WC}	120		150		200		ns
Address to Write Setup Time	t_{AS}	0		0		0		ns
Write Time	t_W	70		90		120		ns
Write Recovery Time	t_{WR}	15		15		15		ns
Data Setup Time	t_{DS}	50		60		80		ns
Data Hold from Write Time	t_{DH}	0		0		0		ns
Output 3-State from Write	t_{OTW}	0	40	0	50	0	60	ns
Chip Selection to End of Write	t_{CW}	100		120		150		ns
Address Valid to End of Write	t_{AW}	100		120		150		ns
Output Active from End of Write	t_{WX}	5		5		5		ns

- Notes:**
1. A Write Cycle occurs during the overlap of a low \overline{CE}_1 , a high CE_2 and a low \overline{WE} .
 2. \overline{OE} may be both high and low in a Write Cycle.
 3. t_{AS} is specified from \overline{CE}_1 , CE_2 or \overline{WE} , whichever occurs last.
 4. t_W is an overlap time of a low \overline{CE}_1 , a high CE_2 and a low \overline{WE} .
 5. t_{WR} , t_{DS} and t_{DH} are specified from \overline{CE}_1 , CE_2 or \overline{WE} , whichever occurs first.
 6. t_{OTW} is specified by the time when DATA OUT is floating, not defined by output level.
 7. When I/O pins are Data output mode, don't force inverse signal to those pins.

WRITE CYCLE



CAPACITANCE

($T_a = 25^\circ\text{C}$, $f = 1\text{MHz}$)

Parameter	Symbol	Min.	Typ.	Max.	Unit
Input/Output Capacitance	$C_{I/O}$			8	pF
Input Capacitance	C_{IN}			6	pF

Note: This parameter is periodically sampled and not 100% tested.